SCS220KGHR

Automotive Grade SiC Schottky Barrier Diode

Datasheet

V_R	1200V
I _F	20A
Q_{C}	65nC

Outline TO-220AC

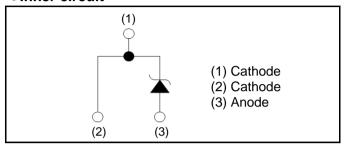
Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

Applications

- On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

•Inner circuit



Packaging specifications

	33 -	
	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS220KG

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	1200	V
Reverse voltage (De	C)	V_R	1200	V
Continuous forward	current (T _c = 133°C)	I _F	20	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		79	А
repetitive forward	ward PW=10ms sinusoidal, T _j =150°C I _{FSM}		59	А
current	PW=10μs square, T _j =25°C		310	А
Repetitive peak forward current		I _{FRM} 83 ^{*1}		А
PW=10ms, T _j =25°C		∫ i²dt	31	A ² s
i ² t value	PW=10ms, T _j =150°C	J I-at	17	A ² s
Total power dissipation		P _D	210 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			Lloit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.4mA	1200	-	-	V
	V _F	I _F =20A,T _j =25°C	-	1.4	1.6	V
Forward voltage		I _F =20A,T _j =150°C	-	1.8	-	V
		I _F =20A,T _j =175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,T _j =25°C	-	20	400	μΑ
		V _R =1200V,T _j =150°C	-	160	-	μΑ
		V _R =1200V,T _j =175°C	-	260	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	1050	-	pF
		V _R =800V,f=1MHz	-	85	-	pF
Total capacitive charge	Q _C	V _R =800V,di/dt=500A/μs	-	65	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	18	-	ns

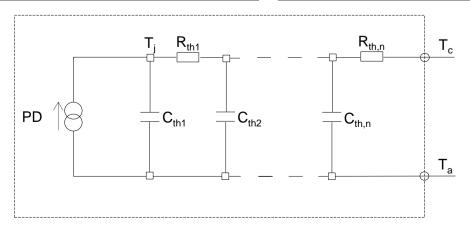
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	0.62	0.71	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	1.59E-01	
R _{th2}	2.74E-01	K/W
R _{th3}	1.87E-01	

Symbol	Value	Unit
C_{th1}	5.03E-03	
C_{th2}	7.27E-03	Ws/K
C_{th3}	1.39E-01	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

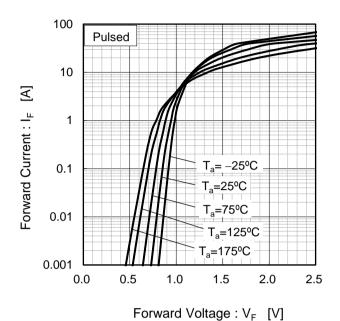
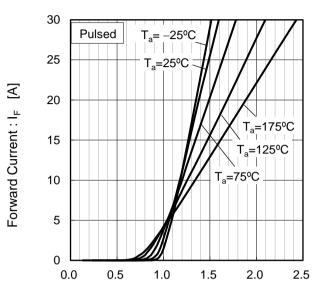


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

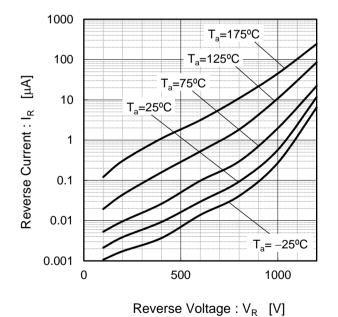
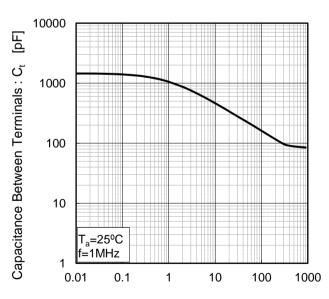


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

• Electrical characteristic curves

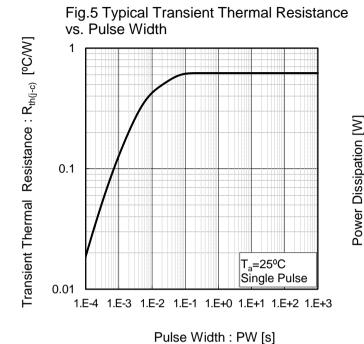
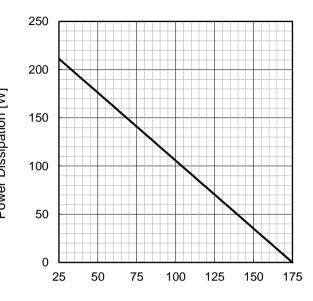
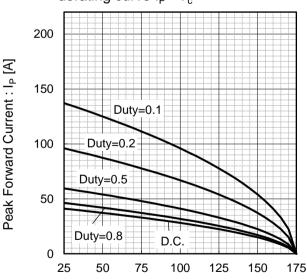


Fig.6 Power Dissipation



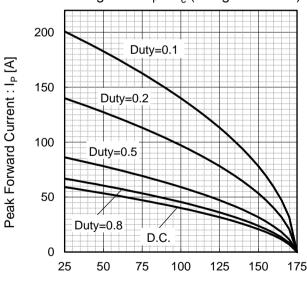
Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve $I_P - T_c$



Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

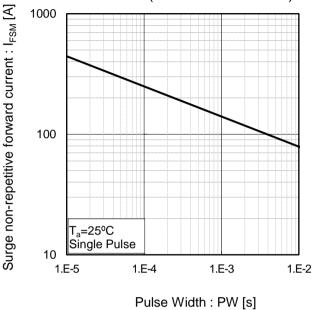
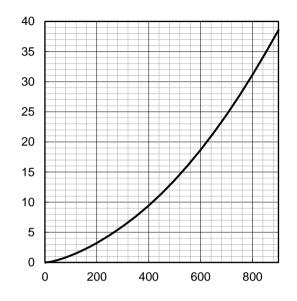


Fig.10 Typical capacitance store energy

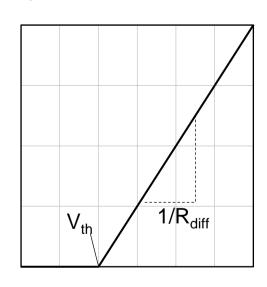


Capacitance stored energy ։ $\mathsf{E}_\mathsf{C}[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.93E-01	V
a ₁	-1.27E-03	V/°C
b ₀	1.83E-02	Ω
b ₁	1.03E-04	Ω/°C
b ₂	6.65E-07	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < °C; I_F < 40 A

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Forward Current: IF

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